

Green Products

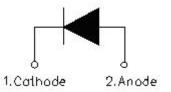
SDUR60P60W ULTRAFAST PLASTIC RECTIFIER

Applications:

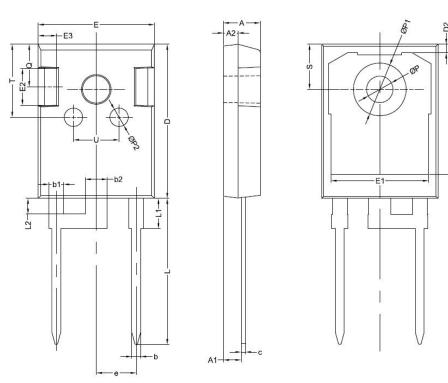
- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In mm



SYMBOL	MIN.	TYP.	MAX.	
Α	4.80	5.00	5.20	
A A1	2.21	2.41	2.61	
A2	1.90	2.00	2.10	
b	1.10	1.20	1.35	
b1		2.00		
b2		3.00		
С	0.55	0.60	0.75	
c D D1	20.80	21.00	21.20	
D1		16.55		
D2 E E1		1.20		
E	15.6	15.8	16.0	
E1		13.30		
E2		5.00		
E3		2.50		
е		5.44		
L L1	19.42	19.92	20.42	
L1		4.13		
L2 P		2.15		
Р	3.50	3.60	3.70	
P1	-	-	7.40	
P2		2.50		
Q		5.80		
Q S T	6.05	6.15	6.25	
T		10.00		
U		6.20		

TO-247AC

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Marking Diagram:



Where XXXXX is YYWWL

SDUR = Device Type

60 = Forward Current (60A)

P = $T_j = 175^{\circ}C$

60 = Reverse Voltage (600V)

W = Configuration

SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SDUR60P60W	TO-247AC	25 pag / tuba
	(Pb-Free)	25 pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{R} \end{array}$	-	600	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =70°C, rectangular wave form	60	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	400	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 30A, Pulse, T _J = 25°C	1.3	-	V
	V F1	@ 60A, Pulse, T _J = 25°C	1.6	1.8	V
Reverse Current*	I _{R1}	@V _R = rated V _R T _J =25°C	0.13	50	uA
	I _{R2}	@V _R = rated V _R T _J =125°C	0.12	1	mA
Reverse Recovery Time	t _{rr1}	I _F =500mA,I _R =1A,and I _m =250mA	36	50	ns
Reverse Recovery Time	t _{rr2}	I_F = 1A; -di/dt = 200A/ μ s; V_R = 30V, T_C = 25°C	40	-	nS
Recovered Charge	Qrr	I_F = 1A; -di/dt = 200A/ μ s; V_R = 30V, T_C = 25°C	58	-	nC

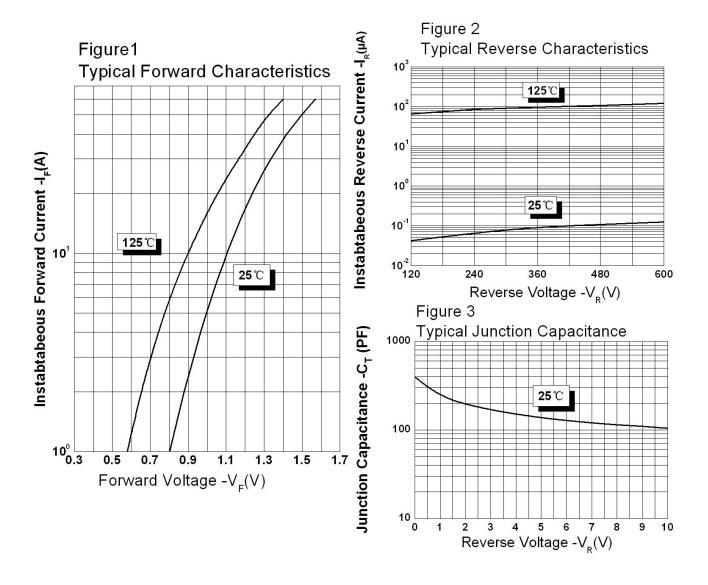
 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Maximum Thermal Resistance Junction to Case	R ₀ JC	DC operation	0.34	°C/W
Approximate Weight	wt	-	6.7	g
Case Style		TO-247AC		



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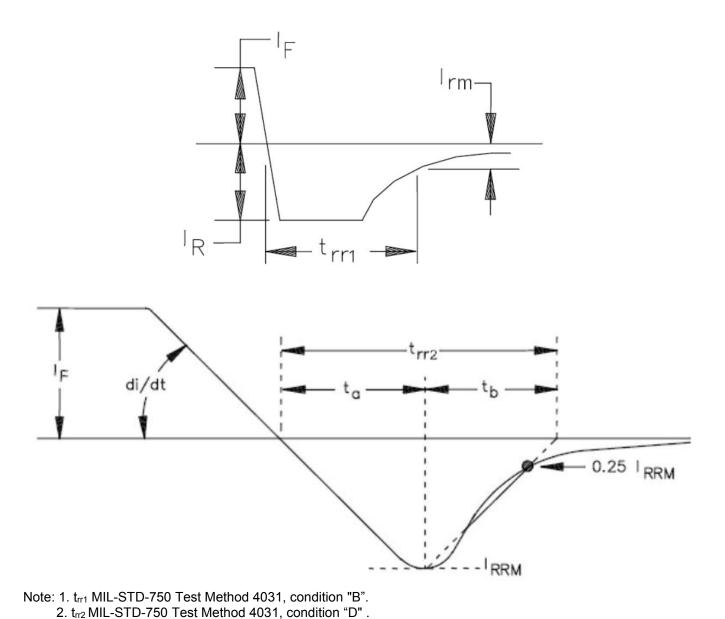


Figure 4 - Reverse Recovery Waveform

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SDUR60P60W



Technical Data Data Sheet N1877, Rev. -

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